



Cite this: RSC Adv., 2017, 7, 40761

Received 1st July 2017  
 Accepted 14th August 2017  
 DOI: 10.1039/c7ra07272d  
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## 1. Introduction

Epoxy resins (EPs) have been widely applied in electrical insulators, printed circuit boards, and packaging materials as a matrix.<sup>1,2</sup> Due to the rapid development in the microelectronics industry, electronic devices continue to move toward miniaturization, putting a large demand on rapid heat release from these small units.<sup>3</sup> However, epoxy resins are poor heat conductors with a heat conduction coefficient of only  $0.2\text{--}0.4\text{ W m}^{-1}\text{ k}^{-1}$ , which cannot meet the heat-dissipation requirements of modern electronics.<sup>4,5</sup> A simple and common method is to introduce high thermal conductivity fillers into the matrix, including oxides ( $\text{Al}_2\text{O}_3$ ,  $\text{SiO}_2$ ,  $\text{ZnO}$ ),<sup>6–8</sup> carbide ( $\text{SiC}$ ),<sup>9</sup> nitrides ( $\text{AlN}$ ,  $\text{BN}$ ,  $\text{Si}_3\text{N}_4$ ),<sup>10,11</sup> and carbon materials (graphene, graphite, diamond, carbon fiber).<sup>12–17</sup> Among the diverse carbon materials, graphene attracts a great deal of attention owing to its fascinating physical properties. For example, graphene<sup>18</sup> has been proposed as a promising heat transfer material due to its excellent in-plane thermal conductivity of  $4100 \pm 500\text{ W m}^{-1}\text{ k}^{-1}$ .<sup>19,20</sup> Unfortunately, the addition of a small amount of graphene will also significantly increase the electrical conductivity of the polymer matrix, which is not desired for purposes of insulation in electronics packaging field. In order to solve this standing problem, oxides ( $\text{SiO}_2$ ,<sup>21,22</sup>  $\text{Al}_2\text{O}_3$ ,<sup>23,24</sup>  $\text{MgO}$ ),<sup>25</sup> and carbide ( $\text{SiC}$ )<sup>26</sup> were coated on the surface of graphene to prevent a direct contact of graphene flakes among each other. Subsequent preparation of composites, however, was found so complex that the loading level of the

additives was fixed to a rather low level and hence not capable of substantially improve the thermal conductivity.

Diamond on the other hand features an outstanding property in electrical insulation but with a high thermal conductivity reaching  $2000\text{ W m}^{-1}\text{ k}^{-1}$ . Modifying diamond with monolayer graphene has been proposed as a prospect way to fabricate an excellent thermal conductor. In deed, several groups have attempted along this direction and, to name a few, Tzeng *et al.*<sup>27</sup> synthesized graphene nanowalls on diamond nanoparticles by chemical vapor deposition (CVD) under a mixed gas stream of  $\text{CH}_4$  and  $\text{H}_2$ ; Garcia *et al.*<sup>28</sup> grew multilayer graphene on diamond surfaces using a thin nickel film that was early deposited by e-beam evaporation.

Inspired by all these works, in this article, we demonstrate a novel epoxy composite that uses graphene-modified-diamond as the filler to improve thermal conductivity but without sacrificing electric insulation of the original resin. Our results show that the thermal conductivity in composites with 70 wt% diamond fillers was  $2.85\text{ W m}^{-1}\text{ k}^{-1}$ , which is 101% better than that of the composites with 70 wt% pure diamond and 1190% better than that of the neat epoxy, with the electrical resistivity maintained at a high level of  $2.2 \times 10^{10}\text{ }\Omega\text{ m}$ . We present the filler fabrication process and later composite characterizations in the rest of this article below.

## 2. Experimental section

### 2.1 Chemicals and materials

Epoxy resin (bisphenol A epoxy resin, E 6002) was provided by Shanghai Chemical Co., Ltd. The curing agent was diethyl methyl benzene diamine (DETDA; provided by Shanghai DE

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Alum Chemical Co., Ltd). Diamond was purchased from Honyuan Diamond Technology Co., Ltd. Nickel powders were purchased from Aladdin Industrial Cooperation. Hydrochloric acid was purchased from Sinopharm Chemical Reagent Co., Ltd. Commercial graphene powders (G5) was purchased from Xia'men Kano Graphene Technology Co., Ltd. All these materials and chemicals were used as received without further purifications.

## 2.2 Experimental processes

**2.2.1 Synthesis of diamond with graphene.** The synthesis of graphene-modified-diamond was accomplished under the condition of vacuum. Particles of diamond and the nickel were used as solid carbon source and catalyst respectively.<sup>29</sup> Diamond particles have a diameter in the range of 10–30  $\mu\text{m}$ ; nickel has a size of 1–5  $\mu\text{m}$ . The mass ratio of diamond and nickel was varied from 100 : 0, 99 : 1, 49 : 1, 19 : 1, 9 : 1, to 1 : 1. These mixtures were set in a silica crucible, and then put in a tube furnace that was pumped to a base pressure below 5 Pa. Later, these powders were heated up to 1273 K and kept at this temperature for 2 h. After cooling to room temperature, the powders were poured into a dilute hydrochloric acid solution and slowly stirred for several hours to get rid of the nickel elements. Finally, these modified diamond fillers were cleaned in distilled water several times to remove nickel chloride and hydrochloric acid before being kept inside a drying oven for later use.

**2.2.2 Preparation of epoxy composites.** The composites were prepared as follows. First, epoxy resin (1.5 g) and surface modified diamond (3.5 g) were mixed together and vigorously stirred for 10 min. Second, curing agent (0.36 g) was added by stirring the mixture for another 10 min. Next, the mixture was poured into a silicone mold and cured *via* the procedures of 117 °C/1 h + 135 °C/0.5 h + 170 °C/2.5 h, respectively. Finally, the resultant composites were demolded and coded as EP (neat epoxy, no filler), D (100 : 0) 0.7/EP, D (99 : 1) 0.7/EP, D (49 : 1) 0.7/EP, D (19 : 1) 0.7/EP, D (9 : 1) 0.7/EP, where 0.7 represents the weight percent of the fillers to epoxy matrix, D (99 : 1) represents the surface modified diamond particles in the condition that the mass ratio between diamond and nickel is 99 : 1.

## 2.3 Characterizations

Samples were characterized by Scanning Electron Microscope (SEM), High-Resolution Transmission Electron Microscope (HRTEM), X-ray diffraction (XRD), Raman spectroscopy and X-ray photoelectron spectroscopy (XPS). SEM was taken on a JSM-6700F field-emitting scanning electron microscope with an operating voltage of 5 kV. High-resolution transmission electron microscope images were taken with JEM-2100 (HRTEM) to investigate the layers of the graphene sheets. X-ray diffraction (XRD) patterns were recorded with a D8-Advance Instrument (Bruker AXS) using Cu K $\alpha$  radiation generated at a voltage of 40 kV and a current of 40 mA. The range of  $2\theta$  was from 10° to 70° with a scanning rate of 5° per minute. Raman spectra was recorded from 500 to 3500  $\text{cm}^{-1}$  on

a Raman spectrometer. XPS was carried out on a ThermoVG RSCAKAB 250X high-resolution X-ray photoelectron spectrometer. The thermal diffusivity ( $\alpha$ ) of the composites was measured by laser flash method using LFA447 (Nano-flash, NETZSCH, Germany). The thermal conductivity was calculated by  $K = \alpha \times \rho \times C_p$ , in which  $C_p$  and  $\rho$  are the heat capacity and density of the composites, respectively. The  $C_p$  was measured using differential scanning calorimeter (DSC 200DSC). The volume resistivity ( $\rho_v$ ) of the materials was collected using the AVO meter (UT70A) and measuring instrument for insulation resistance (ZC36). All the measurements were operated at room temperature.

## 3. Results and discussion

### 3.1 Graphene microstructure and growth mechanism on diamond surface

Fig. 1a, c and e are SEM images of surface modified diamond microparticles. Different amount of graphene was deposited with loading ratio between diamond and nickel catalyst varied between 1 : 1, 9 : 1, and 49 : 1, respectively. Fig. 1b, d and f are enlarged views. When 1 : 1 ratio of diamond and nickel powders were mixed, most diamond surfaces are covered with graphene (Fig. 1a) that are smooth and folded (Fig. 1b). However, when diamond and nickel powders were mixed in other proportions, such as 9 : 1 and 49 : 1, the graphene can not uniformly distributed on the diamond surface anymore; with the decreasing in the number of nickel powders, the amount of graphene grown was less and less. Moreover, the graphene

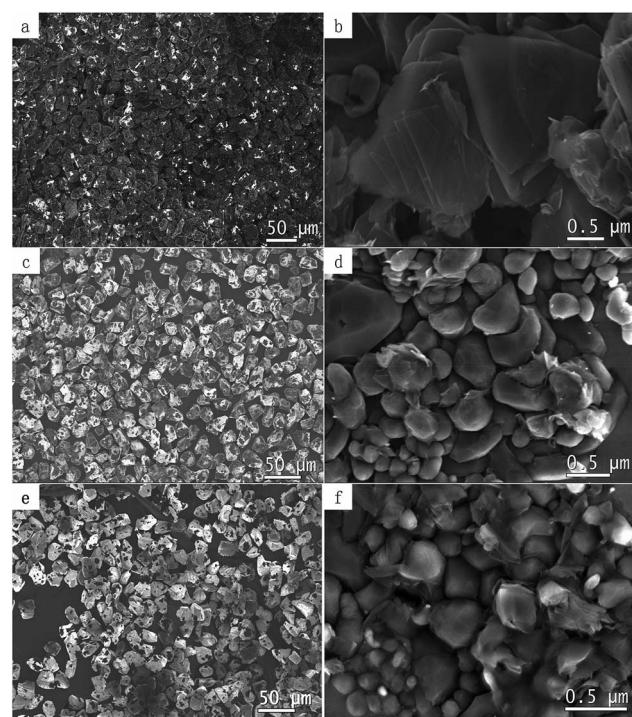


Fig. 1 (a, c, e) SEM images of surface modified diamond microparticles with different coverage of graphene on surfaces, (b, d, f) SEM images of high magnification images.



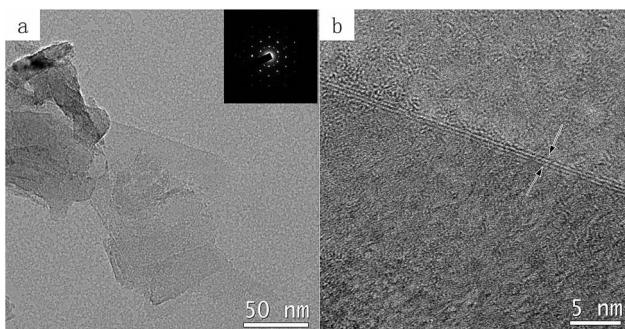


Fig. 2 (a and b) TEM and HRTEM images of graphene on diamond microparticles surface.

changed from a flake-like topography to spherical. Overall, the final amount of the graphene layers on diamond depends on the dosage of catalyst.

Fig. 2a and b demonstrate the morphology and thickness of graphene by TEM and high-resolution TEM images. Note these graphene flakes were intentionally removed from diamond particle surfaces with sonication, this diamond was treated with a very small amount of Ni (Ni/diamond = 1/49). Fig. 2a displays that the graphene sheet is flat. Another information on the thickness of these graphene sheets is provided by HRTEM in Fig. 2b, showing the number of graphene layers is approximately 3. The insert image in Fig. 2a is the corresponding selected area electron diffraction (SAED) pattern, which can further demonstrate the highly ordered crystalline structure of the graphene sheets.

The XRD measurements in the  $2\theta$  range of 10–70° are shown in Fig. 3a, with a diffraction peak appearing at 44° in all the samples. This peak is a signature peak of highly crystalline diamond, which agrees with the observations described previously.<sup>30</sup> After treatment with different proportions of nickel powders, the absence of another peak at around 26.4° confirms the formation of graphene. As illustrated in figure, with the reduction of graphene, the intensity of the peak gradually diminished.

Raman spectra of the graphene on diamond surfaces are shown in Fig. 3b. First, we see a sharp peak at  $1332\text{ cm}^{-1}$ , next to a satellite peak of  $1350\text{ cm}^{-1}$ . The peaks at  $1350$  and  $1580\text{ cm}^{-1}$  have been assigned as the typical D band and G band of graphene respectively.<sup>31–33</sup> The D band is caused by the defect and disorder of graphene. The G band is generated from  $\text{sp}^2$  hybridized carbon bonds. Another 2D band near  $2700\text{ cm}^{-1}$  is the characteristic peak of graphene structure, which can be used to estimate the number of layers of graphene. As revealed in Fig. 3b, the height of the 2D peak is about the same as the G peak when the diamond particles were treated on these conditions that the ratio between diamond and nickel particles were 1 : 1 and 9 : 1, this indicates that the graphene sheet is about 2–3 layers.

In addition, here we measure a single, sharp 2D peak in graphene, roughly 2 times more intense than the G peak when the ratio between diamond and nickel was 49 : 1. This indicates that the graphene sheet is 1–2 layers. The sharp peak at  $1332\text{ cm}^{-1}$  is believed to be from the diamond. From all above, we conclude that the few-layer graphene has successfully grown on the surface of diamond. Furthermore, compared with

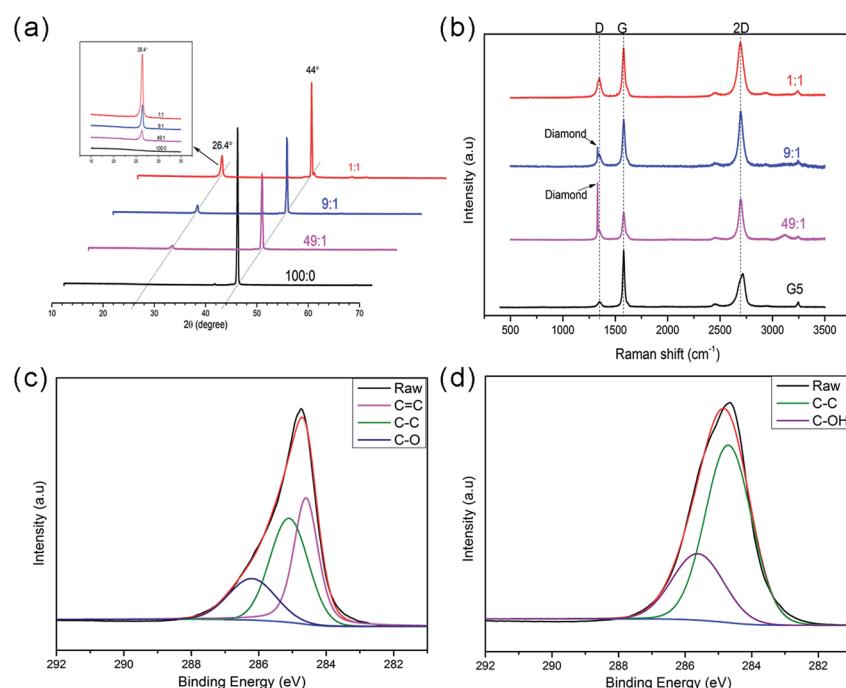


Fig. 3 (a) X-ray diffraction patterns of graphene-modified-diamond under different conditions where the ratio between diamond and nickel catalyst is kept at 1 : 1, 9 : 1, 49 : 1, or 100 : 0; (b) Raman shift of commercial graphene (G5) and graphene-modified-diamond under different conditions where the ratio between diamond and nickel catalyst was kept at 1 : 1, 9 : 1, or 49 : 1; C<sub>1s</sub> XPS spectra of graphene-modified-diamond that was treated with a very small amount of Ni (Ni/diamond = 1/49) (c), pure diamond (d).



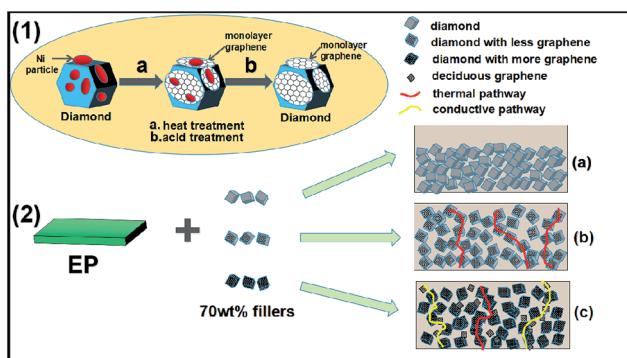


Fig. 4 Schematic diagram of diamond/epoxy composites.

commercial graphene, our samples have rather different 2D peak, where the 2D peak in commercial graphene consists of a relatively wide peak, roughly 1/2 the height of the G peak. Besides, when layers of graphene increase, a modest right shift happened. This shift referred by literature as a sign of thicker sheets of graphene.<sup>33</sup>

The XPS was employed to confirm the nature of the carbon and oxygen bonds appear in the graphene samples (Fig. 3c), the deconvoluted C<sub>1s</sub> XPS spectra of graphene-modified-diamond (Fig. 3c) showed three peaks corresponding to the carbon atoms in different functional groups, the peak at 284.5 eV corresponded to sp<sup>2</sup> C=C hybridization, corresponding to graphitic carbon, the peak centered at around 285.0 eV corresponds to sp<sup>3</sup> C-C hybridization. Another peaks at 286.2 eV is attributed to carbon bonding to oxygen (C-O), indicating some oxygen atoms chemically bond to the graphene that deposited on diamond surface.<sup>29</sup> As revealed in Fig. 3d, the main peak

centered at 284.8 eV is consistent with sp<sup>3</sup> hybridization. The sp<sup>3</sup> hybridization is considered to be derived from the diamond.

Fig. 4(1) is a schematic diagram of the fabrication process for the growth of graphene on the diamond surface. First, during heating process, carbon atoms from diamond can dissolve into the nickel particles. Second, upon cooling, these carbon atoms segregate to the surface of nickel particles, forming larger amount of multilayer and monolayer graphene. Last, the monolayer and multilayer graphene are formed on the diamond surface through the strong C-C σ bonds which were observed before in literatures.<sup>28,29,34</sup>

### 3.2 Thermal conductivity and electrically insulating performance of the epoxy composites

Good dispersion of the fillers in the polymer matrix is an important factor for achieving a desired performance. The dispersion of diamond in the epoxy matrix was characterized by SEM. Cross section images of the epoxy composites bulk are shown in Fig. 5, where Fig. 5a shows the dispersion of pristine diamond in the epoxy matrix and Fig. 5b and c are enlarged view of Fig. 5a. We notice that there were a certain degree of precipitation of diamond particles (Fig. 5c), probably due to a high density of diamond. Fig. 5d-h show the uniform dispersion of modified diamond with graphene in the epoxy matrix, probably due to the C-O bonds on the graphene surface. Therefore, a strong interfacial adhesion is formed because of the better interaction of the graphene-modified-diamond with the epoxy matrix.

Fig. 5f and i are enlarged view of Fig. 5e and h, respectively. This diamond shown in Fig. 5f was treated with a very small amount of Ni (Ni/diamond = 1/49). We found the diamond surface was partially covered with spherical graphene.

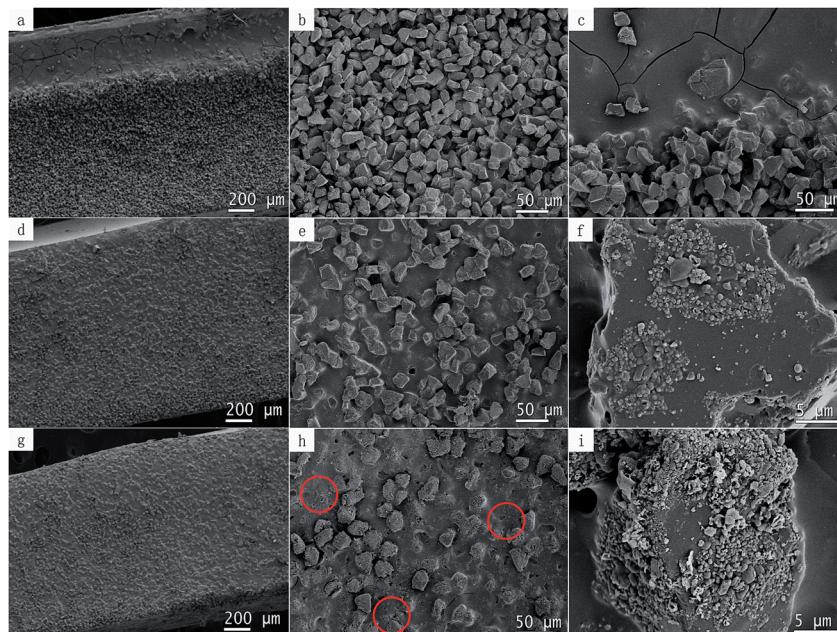


Fig. 5 SEM micrographs of the epoxy composites loaded with 70 wt% of (a, b, c) pure diamond, (d, e, f) treated diamond with a low dosage of catalyst (catalyst/diamond = 1/49) and (g, h, i) treated diamond with a high dosage of catalyst (catalyst/diamond = 1/9).



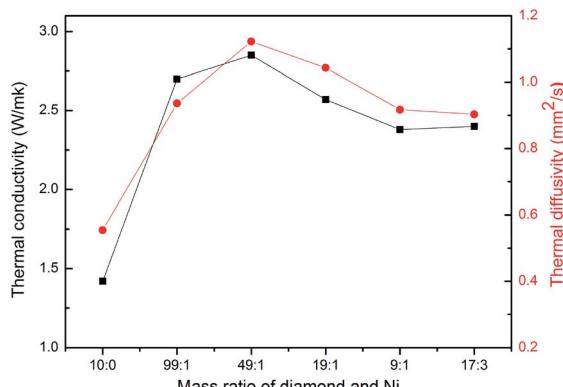


Fig. 6 Thermal diffusivity ( $\alpha$ ) and thermal conductivity ( $\kappa$ ) of 70 wt% diamond/epoxy composites varied with the amount of nickel catalyst during diamond surface treatment.

Interestingly, probably due to a strong carbon–carbon bond, graphene does not fall off easily; and the graphene growth did not seem to damage the diamond that much. Yet, the amount of graphene that grown on diamond surface was raised to a higher level when the loading ratio of catalyst is increased to 1/9. We see, some of the graphene can be stripped off and dispersed in epoxy resin, as shown in Fig. 5h and 4(2c). However, this was achieved with a serious damage from the catalyst erosion over diamond.

Both the thermal conductivity and thermal diffusivity of the epoxy composites are given in Fig. 6. When the diamond particles were pretreated with different dosage of catalyst, both terms changed with the amount of the nickel catalyst or the amount of graphenes. Specifically, the thermal conductivity ( $\alpha$ ) and thermal diffusivity ( $\kappa$ ) increased first, then passed through a maximum, and later decreased at larger proportion of catalyst. It is worth noting that a high thermal diffusivity ( $1.12 \text{ mm}^2 \text{ s}^{-1}$ ) was obtained with 70 wt% modified diamond (catalyst/diamond = 1/49)/epoxy composites as shown in Fig. 6. Corresponding thermal conductivity is  $2.85 \text{ W m}^{-1} \text{ K}^{-1}$ , which corresponds to a 101% increase compared to the value for the composite with 70 wt% pure diamond, and 1190% better than that of pure epoxy (pure epoxy resin had a thermal conductivity of  $0.2 \text{ W m}^{-1} \text{ K}^{-1}$ ).<sup>35</sup> Two aspects are explored to illustrate this

relatively large improvement. First, thermal conductivity of graphene is intrinsically higher than diamond, the addition of graphene will minimize the interfacial thermal resistance with the epoxy resin. Second, we suspect a graphene decorated diamond disperses better probably due to the C–O bonds on the graphene surface. Therefore, a strong interfacial adhesion is formed between the filler and epoxy, making it easier to form a thermal pathway, as shown in Fig. 4 and 2b.

However, both of these values decreased when diamond was mixed with a larger amount of catalyst. Since graphene was formed under the condition of catalyst erosion over the diamond, the destruction of diamond will be more severe at a high catalyst loading and this results in the deterioration of the thermal conductivity.

Fig. 7 shows the volumetric electrical resistivity of the epoxy/diamond composites, where a high value of  $2.20 \times 10^{10} \Omega \text{ m}$  was received for composites having 70 wt% pure diamond. Meanwhile, this value remained about the same for composites with 70 wt% modified diamond, as shown in Fig. 7. However, when the diamond was treated in the condition of a high catalyst loading of 1 : 9, the electrical resistivity declined sharply by 9 orders of magnitude and reached an extremely low value of  $1.7 \times 10^1 \Omega \text{ m}$ , which indicates that the electrical percolation network had already formed. Perhaps, some of the graphene has been stripped off, making it easier to form a conductive pathway, as marked by the red circle in the Fig. 5h.

## 4. Conclusions

In summary, the graphene-modified-diamond enhances contact area for thermal reinforcement in polymer matrix. After the pretreatment of diamond with a low dosage of catalyst (1/49), the thermal conductivity with 70 wt% fillers reached  $2.85 \text{ W m}^{-1} \text{ K}^{-1}$ , which corresponds to a 101% increase compared to the value of the composites with 70 wt% pure diamond, and 1190% better than that of pure epoxy. Moreover, the electrical insulation of the diamond powder effectively inhibited the electron transport. The prepared epoxy composites exhibited both outstanding thermal conductivity and electrical insulation, which could lead to enhanced application in the field of thermal management for electrical packaging.

## Conflicts of interest

There are no conflicts to declare.

## Acknowledgements

This work was financially supported by Natural Science Foundation of China (51373059), Science Foundation of Xiamen (3502Z20150046), science and technology innovation team of Huaqiao University (Z14X0046), and The Research Center of Graphene Powder & Composites of Fujian Province.

## Notes and references

1. S. Rimdusit and H. Ishida, *Polymer*, 2000, **41**, 7941–7949.

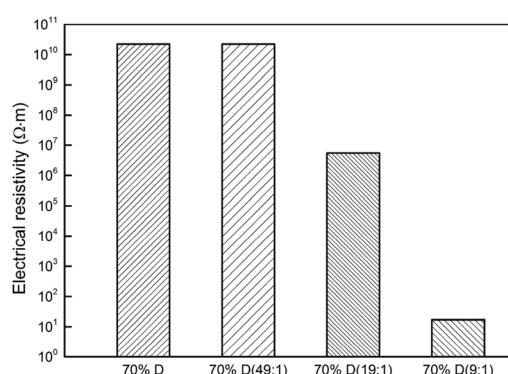


Fig. 7 Volumetric electrical resistivity of the epoxy composites.



- 2 S. Zhao, L. S. Schadler, R. Duncan, H. Hillborg and T. Auletta, *Compos. Sci. Technol.*, 2008, **68**, 2965–2975.
- 3 H. Chen, V. V. Ginzburg, J. Yang, Y. Yang, W. Liu, Y. Huang, L. Du and B. Chen, *Prog. Polym. Sci.*, 2016, **59**, 41–85.
- 4 S. Ganguli, A. K. Roy and D. P. Anderson, *Carbon*, 2008, **46**, 806–817.
- 5 M. J. Assael, K. D. Antoniadis and D. Tzetzis, *Compos. Sci. Technol.*, 2008, **68**, 3178–3183.
- 6 S. Choi and J. Kim, *Composites, Part B*, 2013, **51**, 140–147.
- 7 Y. Heo, H. Im, J. Kim and J. Kim, *J. Nanopart. Res.*, 2012, **14**, 1–10.
- 8 N. Chisholm, H. Mahfuz, V. K. Rangari, A. Ashfaq and S. Jeelani, *Compos. Struct.*, 2005, **67**, 115–124.
- 9 T. L. Li and S. L. Hsu, *J. Phys. Chem. B*, 2010, **114**, 6825–6829.
- 10 Z. Shi, M. Radwan, S. Kirihara, Y. Miyamoto and Z. Jin, *Appl. Phys. Lett.*, 2009, **95**, 224104.
- 11 F. Yang, X. Zhao and P. Xiao, *J. Eur. Ceram. Soc.*, 2010, **30**, 3111–3116.
- 12 V. Goyal and A. A. Balandin, *Appl. Phys. Lett.*, 2012, **100**, 073113.
- 13 K. Chu, W. Li, C. Jia and F. I. Tang, *Appl. Phys. Lett.*, 2012, **101**, 211903.
- 14 Y. M. Chen and J. M. Ting, *Carbon*, 2002, **40**, 359–362.
- 15 L. M. Veca, M. J. Meziani, W. Wang, X. Wang, F. Lu, P. Zhang, Y. Lin, R. Fee, J. W. Connell and Y. P. Sun, *Adv. Mater.*, 2009, **21**, 2088–2092.
- 16 S. Ganguli, A. K. Roy and D. P. Anderson, *Carbon*, 2008, **46**, 806–817.
- 17 W. S. Lee and J. Yu, *Diamond Relat. Mater.*, 2005, **14**, 1647–1653.
- 18 K. S. Novoselov, A. K. Geim, S. V. Morozov, D. Jiang, Y. Zhang, S. V. Dubonos, I. V. Grigorieva and A. A. Firsov, *science*, 2004, **306**, 666–669.
- 19 A. A. Balandin, S. Ghosh, W. Bao, I. Calizo, D. Teweldebrhan, F. Miao and C. N. Lau, *Nano Lett.*, 2008, **8**, 902–907.
- 20 S. Ghosh, W. Bao, D. L. Nika, S. Subrina, E. P. Pokatilov, C. N. Lau and A. A. Balandin, *Nat. Mater.*, 2010, **9**, 555–558.
- 21 X. Pu, H. B. Zhang, X. Li, C. Gui and Z. Z. Yu, *RSC Adv.*, 2014, **4**, 15297–15303.
- 22 M. C. Hsiao, C. C. M. Ma, J. C. Chiang, K. K. Ho, T. Y. Chou, X. Xie, C. H. Tsai, L. H. Chang and C. K. Hsieh, *Nanoscale*, 2013, **5**, 5863–5871.
- 23 R. Sun, H. Yao, H. B. Zhang, Y. Li, Y. W. Mai and Z. Z. Yu, *Compos. Sci. Technol.*, 2016, **137**, 16–23.
- 24 R. Qian, J. Yu, C. Wu, X. Zhai and P. Jiang, *RSC Adv.*, 2013, **3**, 17373–17379.
- 25 F. Du, W. Yang, F. Zhang, C. Y. Tang, S. Liu, L. Yin and W. C. Law, *ACS Appl. Mater. Interfaces*, 2015, **7**, 14397–14403.
- 26 Y. Wang, J. Yu, W. Dai, D. Wang, Y. Song, H. Bai, X. Zhou, C. Li, C. T. Lin and N. Jiang, *RSC Adv.*, 2014, **4**, 59409–59417.
- 27 Y. Tzeng, W. L. Chen, C. Wu, J. Y. Lo and C. Y. Li, *Carbon*, 2013, **53**, 120–129.
- 28 J. M. Garcia, R. He, M. P. Jiang, P. Kim, L. N. Pfeiffer and A. Pinczuk, *Carbon*, 2011, **49**, 1006–1012.
- 29 H. H. Zou, H. Bai, J. H. Yu, Y. Wang, Q. L. Liao, K. Nishimura, L. M. Zeng and N. Jiang, *Composites, Part B*, 2015, **73**, 57–60.
- 30 M. Pandey, R. D'Cunha and A. K. Tyagi, *J. Alloys Compd.*, 2002, **333**, 260–265.
- 31 S. Kurita, A. Yoshimura, H. Kawamoto, T. Uchida, K. Kojima, M. Tachibana, P. Molina-Morales and H. Nakai, *J. Appl. Phys.*, 2005, **97**, 104320.
- 32 Z. Ni, H. Fan, Y. Feng, Z. Shen, B. Yang and Y. Wu, *J. Chem. Phys.*, 2006, **124**, 204703.
- 33 A. C. Ferrari, J. Meyer, V. Scardaci, C. Casiraghi, M. Lazzeri, F. Mauri, S. Pisacane, D. Jiang, K. Novoselov and S. Roth, *Phys. Rev. Lett.*, 2006, **97**, 187401.
- 34 Q. Yuan, H. Hu, J. Gao, F. Ding, Z. Liu and B. I. Yakobson, *J. Am. Chem. Soc.*, 2011, **133**, 16072–16079.
- 35 M. Donnay, S. Tzavalas and E. Logakis, *Compos. Sci. Technol.*, 2015, **110**, 152–158.